

DOCKET NO.: 288839US0PCT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

IN RE APPLICATION OF:

GROUP: 1715

Ekkehard MUEH, et al.

SERIAL NO: 10/586,675

EXAMINER: MILLER, JR, JOSEPH  
ALBERT

FILED: July 20, 2006

FOR: SILICON COMPOUNDS FOR PRODUCING SIO<sub>2</sub>-CONTAINING  
INSULATING LAYERS ON CHIPS

**RESTRICTION RESPONSE**

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

Sir:

In response to the Restriction Requirement dated October 13, 2010, Applicants elect, with traverse, Group I, Claims 1-3 and 6 (drawn to process), for examination.

Applicants also provisionally elect, with traverse, for examination purposes only, the following species (at least claims 1-3 and 6 readable thereon):

- A) vinyltrimethoxysilane; and
- B) CVD.

**Remarks/Arguments** begin on page 2 of this paper.